

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74LVX04F, TC74LVX04FN, TC74LVX04FT**HEX INVERTER**

The TC74LVX04 is a high speed CMOS HEX INVERTER fabricated with silicon gate C²MOS technology.

Designed for use in 3.3 Volt systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

This device is suitable for low voltage and battery operated systems.

The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output.

An input protection circuit ensures that 0 to 7V can be applied to the input pins without regard to the supply voltage.

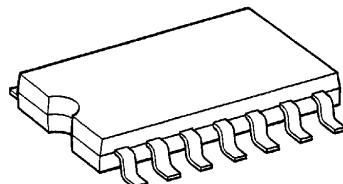
This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

FEATURES

- High speed : $t_{pd} = 4.1\text{ns}$ (Typ.) ($V_{CC} = 3.3\text{V}$)
- Low power dissipation : $I_{CC} = 2\mu\text{A}$ (Max.) ($T_a = 25^\circ\text{C}$)
- Input voltage level : $V_{IL} = 0.8\text{V}$ (Max.) ($V_{CC} = 3\text{V}$)
 $V_{IH} = 2.0\text{V}$ (Min.) ($V_{CC} = 3\text{V}$)
- Power down protection is provided on all inputs.
- Balanced propagation delays : $t_{pLH} \approx t_{pHL}$
- Low noise : $V_{OLP} = 0.5\text{V}$ (Max.)
- Pin and function compatible with 74HC04

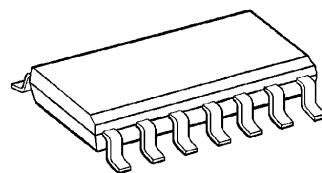
(Note) The JEDEC SOP (FN) is not available in Japan.

TC74LVX04F



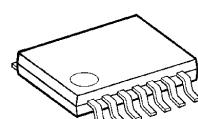
SOP14-P-300-1.27

TC74LVX04FN



SOL14-P-150-1.27

TC74LVX04FT



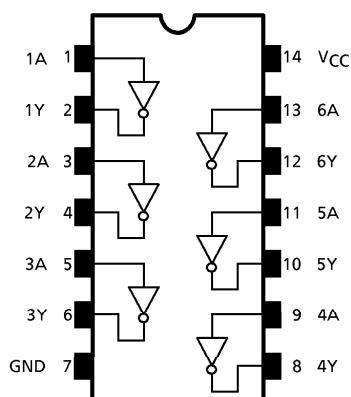
TSSOP14-P-0044-0.65

Weight

| | |
|---------------------|----------------|
| SOP14-P-300-1.27 | : 0.18g (Typ.) |
| SOL14-P-150-1.27 | : 0.12g (Typ.) |
| TSSOP14-P-0044-0.65 | : 0.06g (Typ.) |

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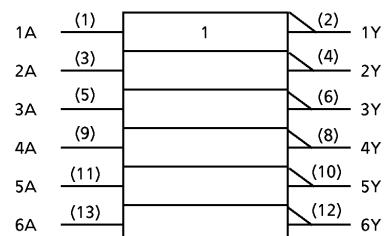
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PIN ASSIGNMENT

(TOP VIEW)

TRUTH TABLE

| INPUTS | OUTPUTS |
|--------|---------|
| A | Y |
| L | H |
| H | L |

IEC LOGIC SYMBOL**MAXIMUM RATINGS**

| PARAMETER | SYMBOL | RATING | UNIT |
|------------------------------|-----------|----------------------|------|
| Supply Voltage Range | V_{CC} | -0.5~7.0 | V |
| DC Input Voltage | V_{IN} | -0.5~7.0 | V |
| DC Output Voltage | V_{OUT} | -0.5~ V_{CC} + 0.5 | V |
| Input Diode Current | I_{IK} | -20 | mA |
| Output Diode Current | I_{OK} | ± 20 | mA |
| DC Output Current | I_{OUT} | ± 25 | mA |
| DC V_{CC} / Ground Current | I_{CC} | ± 50 | mA |
| Power Dissipation | P_D | 180 | mW |
| Storage Temperature | T_{stg} | -65~150 | °C |

RECOMMENDED OPERATING CONDITIONS

| PARAMETER | SYMBOL | RATING | UNIT |
|--------------------------|-----------|-------------|------|
| Supply Voltage | V_{CC} | 2.0~3.6 | V |
| Input Voltage | V_{IN} | 0~5.5 | V |
| Output Voltage | V_{OUT} | 0~ V_{CC} | V |
| Operating Temperature | T_{opr} | -40~85 | °C |
| Input Rise And Fall Time | dt/dv | 0~100 | ns/V |

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- The information contained herein is subject to change without notice.

ELECTRICAL CHARACTERISTICS

DC characteristics

| PARAMETER | SYM-BOL | TEST CONDITION | V _{CC} (V) | Ta = 25°C | | | Ta = - 40~85°C | | UNIT | |
|--------------------------|-----------------|--|-----------------------------------|---------------------------|------|------|----------------|------|-------|----|
| | | | | MIN. | TYP. | MAX. | MIN. | MAX. | | |
| Input Voltage | "H" Level | V _{IH} | | 2.0 | 1.5 | — | — | 1.5 | — | V |
| | | | | 3.0 | 2.0 | — | — | 2.0 | — | |
| | | | | 3.6 | 2.4 | — | — | 2.4 | — | |
| | "L" Level | V _{IL} | | 2.0 | — | — | 0.5 | — | 0.5 | |
| | | | | 3.0 | — | — | 0.8 | — | 0.8 | |
| | | | | 3.6 | — | — | 0.8 | — | 0.8 | |
| Output Voltage | "H" Level | V _{OH} | V _{IN} = V _{IL} | I _{OH} = - 50 μA | 2.0 | 1.9 | 2.0 | — | 1.9 | V |
| | | | | I _{OH} = - 50 μA | 3.0 | 2.9 | 3.0 | — | 2.9 | |
| | | | | I _{OH} = - 4mA | 3.0 | 2.58 | — | — | 2.48 | |
| | "L" Level | V _{OL} | V _{IN} = V _{IH} | I _{OL} = 50 μA | 2.0 | — | 0.0 | 0.1 | — | |
| | | | | I _{OL} = 50 μA | 3.0 | — | 0.0 | 0.1 | — | |
| | | | | I _{OL} = 4mA | 3.0 | — | — | 0.36 | — | |
| Input Leakage Current | I _{IN} | V _{IN} = 5.5V or GND | | 3.6 | — | — | ± 0.1 | — | ± 1.0 | μA |
| Quiescent Supply Current | I _{CC} | V _{IN} = V _{CC} or GND | | 3.6 | — | — | 2.0 | — | 20.0 | μA |

AC characteristics (Input t_r = t_f = 3ns)

| PARAMETER | SYM-BOL | TEST CONDITION | V _{CC} (V) | C _L (pF) | Ta = 25°C | | | Ta = - 40~85°C | | UNIT | |
|-------------------------------|--|----------------|---------------------|---------------------|-----------|------|------|----------------|------|------|--|
| | | | | | MIN. | TYP. | MAX. | MIN. | MAX. | | |
| Propagation Delay Time | t _{pLH} | | 2.7 | 15 | — | 5.4 | 10.1 | 1.0 | 12.5 | ns | |
| | | | | 50 | — | 7.9 | 13.6 | 1.0 | 16.0 | | |
| | t _{pHL} | | 3.3 ± 0.3 | 15 | — | 4.1 | 6.2 | 1.0 | 7.5 | | |
| | | | | 50 | — | 6.6 | 9.7 | 1.0 | 11.0 | | |
| Output To Output Skew | t _{osLH} t _{osHL} | (Note 1) | 2.7 | 50 | — | — | 1.5 | — | 1.5 | ns | |
| | | | 3.3 ± 0.3 | 50 | — | — | 1.5 | — | 1.5 | | |
| Input Capacitance | C _{IN} | (Note 2) | | — | — | 4 | 10 | — | 10 | pF | |
| Power Dissipation Capacitance | C _{PD} | (Note 3) | | — | — | 18 | — | — | — | pF | |

(Note 1) Parameter guaranteed by design.

(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)

(Note 2) Parameter guaranteed by design.

(Note 3) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

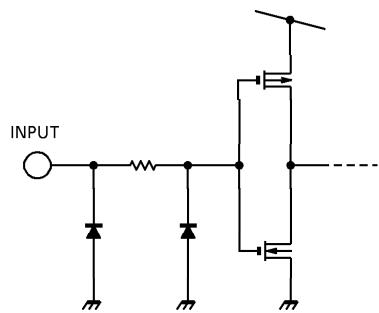
Average operating current can be obtained by the equation :

$$I_{CC(\text{opr.})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 6 \text{ (per Gate)}$$

Noise characteristics ($T_a = 25^\circ\text{C}$, Input $t_r = t_f = 3\text{ns}$, $C_L = 50\text{pF}$)

| PARAMETER | SYMBOL | TEST CONDITION | V_{CC} (V) | TYP. | LIMIT | UNIT |
|---|-----------|----------------|--------------|------|-------|------|
| | | | 3.3 | | | |
| Quiet Output Maximum Dynamic V_{OL} | V_{OLP} | | 3.3 | 0.3 | 0.5 | V |
| Quiet Output Minimum Dynamic V_{OL} | V_{OLV} | | 3.3 | -0.3 | -0.5 | V |
| Minimum High Level Dynamic Input Voltage | V_{IHD} | | 3.3 | — | 2.0 | V |
| Maximum Low Level Dynamic Input Voltage | V_{ILD} | | 3.3 | — | 0.8 | V |

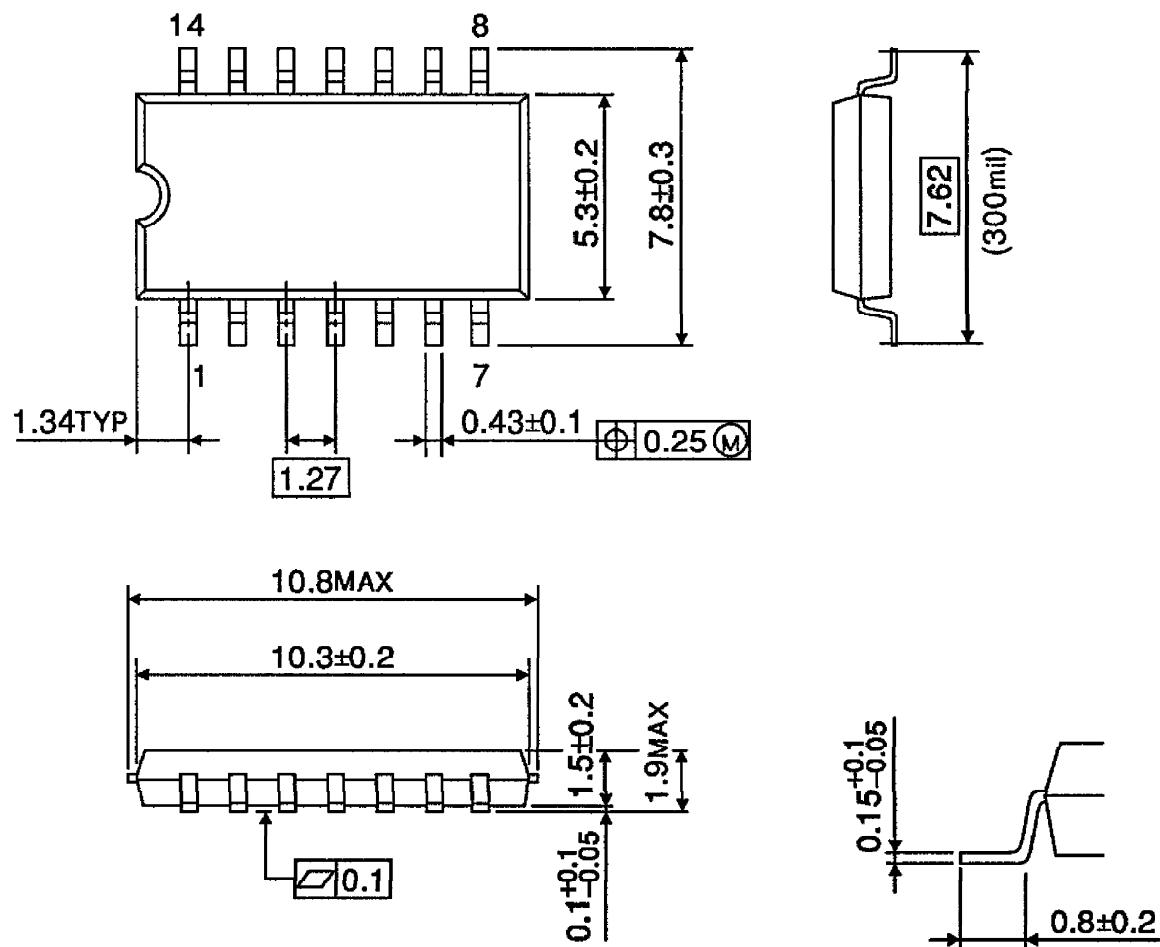
INPUT EQUIVALENT CIRCUIT



OUTLINE DRAWING

SOP14-P-300-1.27

Unit : mm

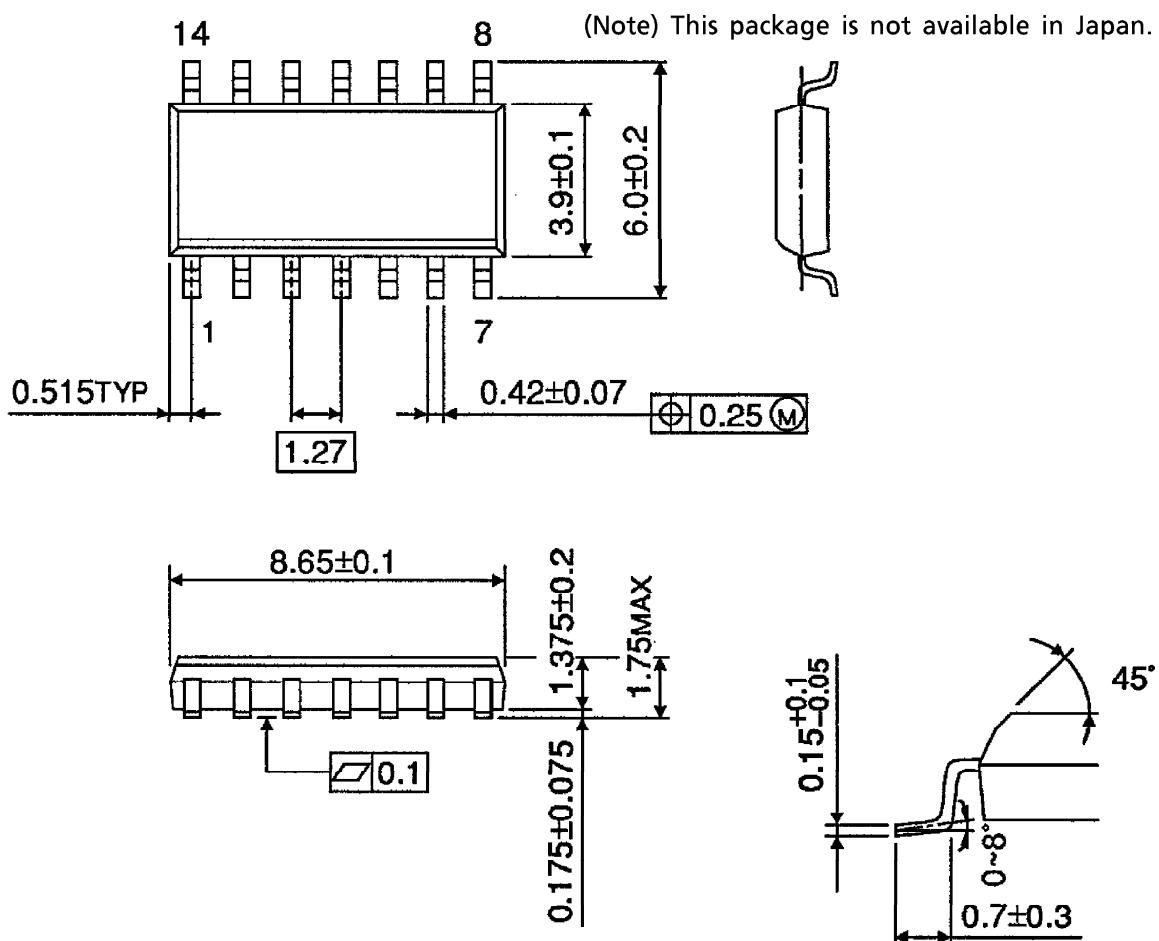


Weight : 0.18g (Typ.)

OUTLINE DRAWING

SOL14-P-150-1.27

Unit : mm

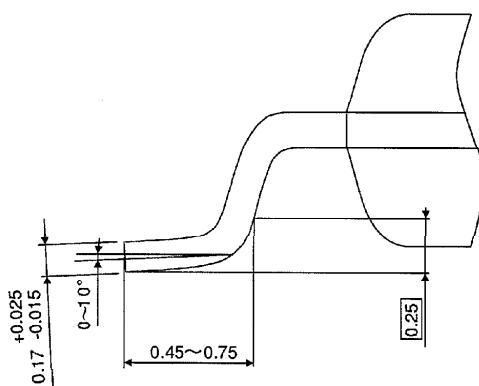
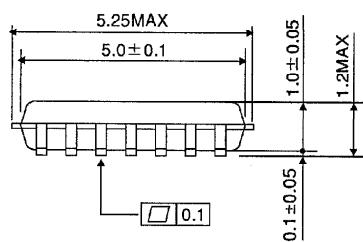
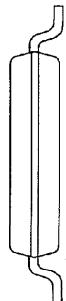
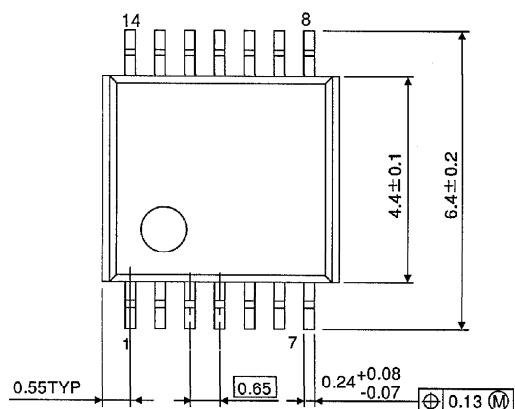


Weight : 0.12g (Typ.)

OUTLINE DRAWING

TSSOP14-P-0044-0.65

Unit : mm



Weight : 0.06g (Typ.)